Littelfuse Power

# LSIC2SD065D16A 650 V, 16 A SiC Schottky Barrier Diode

HF Rohs 🗭



## Circuit Diagram TO-263-2L



## Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

## Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature

### Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies

#### Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = 100 Pb-free lead plating

switch	ing	behav	vior
-	. •		

Extremely fast,

 Dramatically reduced switching losses compared to Si bipolar diodes

• Excellent surge capability

temperature-independent

#### • Solar inverters

- Industrial motor drives
- EV charging stations

## **Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	650	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	650	V	
		T <sub>c</sub> = 25 °C	38	А	
Continuous Forward Current	I <sub>F</sub>	T <sub>c</sub> = 135 °C	17.2		
		$T_c = 140 \text{ °C}$	16		
Non-Repetitive Forward Surge Current	   <sub>FSM</sub>	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	70	A	
Power Dissipation	D	$T_c = 25 \text{ °C}$	125	- W	
Fower Dissipation	P <sub>Tot</sub>	$T_c = 110 \text{ °C}$	54		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to 150	°C	
SolderingTemperature	T <sub>SOLD</sub>	-	260	°C	

Electrical Characteristics (T <sub>J</sub> = 25 °C unless otherwise specified)							
			Value				
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 16 Α, Τ <sub>J</sub> = 25 °C	-	1.5	1.8	N	
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 175 °C	-	1.85	-	V	
Reverse Current	I <sub>R</sub> -	V <sub>R</sub> = 650 V , T <sub>J</sub> = 25 °C	-	<1	50	μA	
		V <sub>R</sub> = 650 V , T <sub>J</sub> = 175 °C	-	55	-		
Total Capacitance	C	V <sub>B</sub> = 1 V, f = 1 MHz	-	730	-		
		V <sub>R</sub> = 200 V, f = 1 MHz	-	92	-	pF	
		V <sub>R</sub> = 400 V, f = 1 MHz	-	66	-		
Total Capacitive Charge	Q <sub>c</sub>	$V_{R} = 400 \text{ V},  Q_{C} = \int_{0}^{V_{R}} C(V) dV$	-	48	-	nC	

Thermal Characteristics						
Characteristics	Symbol	Value	Unit			
Thermal Resistance	R <sub>euc</sub>	1.2	°C/W			



Figure 2: Typical Reverse Characteristics



#### **Figure 3: Power Derating**



## Figure 5: Capacitance vs. Reverse Voltage







#### Figure 4: Current Derating



#### Figure 6: Capacitive Charge vs. Reverse Voltage



## Figure 8: Transient Thermal Impedance



## Dimensions-Package TO-263-2L



Part N	lumberin	g and Ma	rkina S	vstem
I al L I V	uniberin	y anu wa	iking o	yatem



- = SiC Diode = Gen2
- = Schottky Diode
- = Voltage Rating (650 V)
- = TO-263 Package (2 Lead) = Current Rating (16 A)
- = Year
- = Week
- = Special Code ZZZZZ-ZZ = Lot Number

Symbol	Millimeters				
Symbol	Min	Nom	Max		
А	4.30	4.50	4.70		
A1	0.00	-	0.25		
b	0.70	0.80	0.90		
b1	1.17	1.27	1.37		
С	0.46	0.50	0.60		
c1	1.25	1.30	1.40		
D	9.00	9.20	9.40		
D1	6.50	6.70	6.90		
Е	9.80	10.00	10.20		
E1	7.80	8.00	8.20		
E2	9.70	9.90	10.10		
е	5.08 BSC				
Н	15.00	15.30	15.60		
L	2.00	2.30	2.60		
L1	1.00	1.20	1.40		
L2	0.254 BSC				

## **Packing Option**

Part Number	Part Number Marking		M.O.Q
LSIC2SD065D16A	SIC2SD065D16	Tape and Reel	800



## GEN2 SiC Schottky Diode LSIC2SD065D16A, 650 V, 16 A, TO-263-2L (D2PAK)

#### **TO-263 Carrier Reel Specifications**



Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, Components intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.